

1 INTRODUCTION

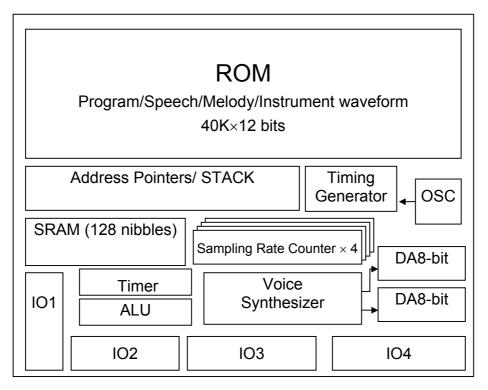
SN66012B is a 12 seconds single chip 4-channel voice synthesizer IC that contains I/O pins and a tiny controller. By programming through the tiny controller, users' applications including section combination, trigger modes, output status, high performance melody, multiple voices, and other logic functions can be implemented.

2 FEATURES

- Single power supply 2.4V 5.1V
- Built in a tiny controller
- 12 seconds voice capacity are provided
- One 4-bit input port, two 4-bit I/O ports and one 4-bit output port are provided
- 128*4 bits RAM are provided
- Maximum 40k program ROM is provided
- Readable ROM code data
- Built in a high quality speech synthesizer
- Four independent voice channels
- Adaptive playing speed from 4k-40kHz is provided for all 4 channels individually
- Automatic repetition for every channel
- A 6-bit*8-bit Multiplier is embed to modulate the volume of synthesized voices
- Two digital mixers (with saturation control) are provided
- Two 8-bit current output DA converters (Channel 1 + Channel 2 → DA1, Channel 3 + Channel 4 → DA2)
- System clock: 2M Hz (RC-type or Crystal Option)
- Low Voltage Reset



3 Block Diagram



4 PIN ASSIGNMENT

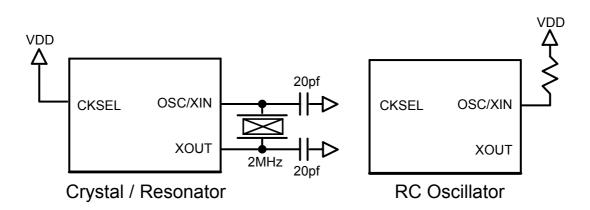
Symbol	I/O	Function Description			
P13, P12, P11, P10	I	Bit3 ~ Bit0 of input port 1			
P23, P22, P21, P20	I/O	Bit3 ~ Bit0 of I/O port 2			
P33, P32, P31, P30	I/O	Bit3 ~ Bit0 of I/O port 3			
P43, P42, P41, P40	0	Bit3 ~ Bit0 of output port 4			
VDD	I	Positive power supply			
GND	Ι	Negative power supply			
OSC/XIN	I	Oscillator / Crystal In			
XOUT	0	Crystal Out			
CKSEL	Ι	Clock type select			
		'L' or floating \rightarrow RC oscillator			
		'H' →Crystal			
VO1	0	D/A current output, for channel 1 and 2			
VO2	0	D/A current output, for channel 3 and 4			



5 FUNCTION DESCRIPTIONS

5.1. Oscillator

SN66012B accepts crystal oscillator / ceramic resonator or RC type oscillator (selected by pin CKSEL) for system clock. The typical circuit diagrams for oscillator are listed as follows.



5.2. ROM

SN66012B contains 40K word (12-bit) internal ROM. Program, voices, melodies, data, and instrument waveforms share the same ROM with the others.

5.3. RAM

SN66012B contains 128 nibble RAM. The 128 nibble RAM is separated into two pages (page 0 and page 1). An implicit page indicator is utilized to specify page address. Two instructions, PAGE0 and PAGE1, can switch the page indicator. All 64 nibbles of each page can be accessed by direct mode (to specify M0 ~ M63 in the data transfer type instructions.)

5.4. Power Down Mode

"End" instruction will let SN66012B enter power down mode and consumer very little amount of current. (<2uA @VDD=3V and <5uA @VDD=5V) After SN66012B enters power down mode, any valid data transition (L \rightarrow H or H \rightarrow L) occurring on any input ports or IO ports (P1, P2, and P3) lead SN66012B back to normal operation mode.



5.5. Sampling Rate Counters

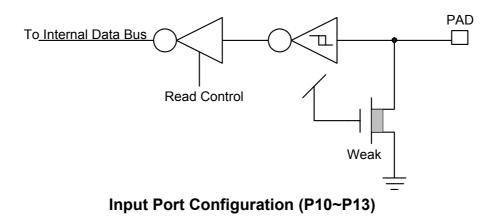
4 independent sampling rate counters are dedicated to 4 individual voice channels to play voices with different playing rates. The playing rate is programmable from 4KHz to 40KHz. The resolution of sampling period of each sampling rate counter is 0.25 uS. This feature helps SN66012B play sounds with accurate pitches in the case of music instrument synthesis.

5.6. Auto repetition

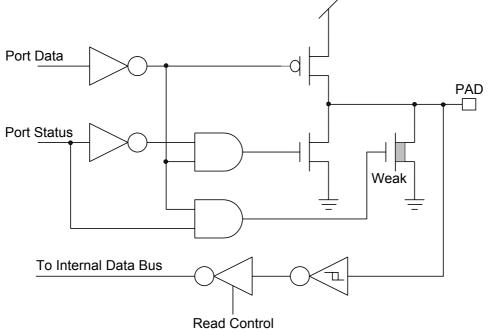
Auto repetition function helps SN66012B realize a "looping" sound automatically by hardware without any software effort. Auto repetition function is a very useful mechanism to implement "Sustain" sound in instrument synthesis. All 4 channels are equipped with this function. Arbitrary lengths of looping sound are accepted by SN66012B.

5.7. I/O Ports

P1 is a 4-bit input port, P2/P3 are two 4-bit I/O ports and P4 is a 4-bit output port. Any bit of P2 and P3 can be programmed to be input or output individually. Any valid data transition ($H \rightarrow L \text{ or } L \rightarrow H$) of P1, P2 and P3 can reactivate the chip when it is in power-down stage.

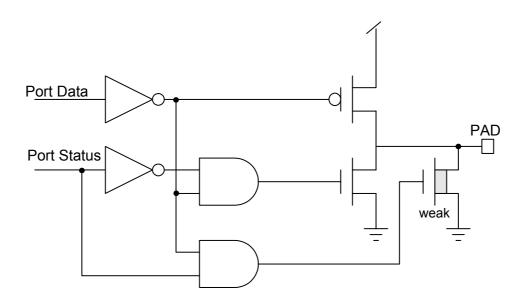






Reau Control





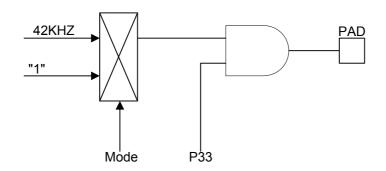
Output Port Configuration (P40~P43)

Note: All weak N-MOS's can serve as pull-low resistors.



5.8. IR Function

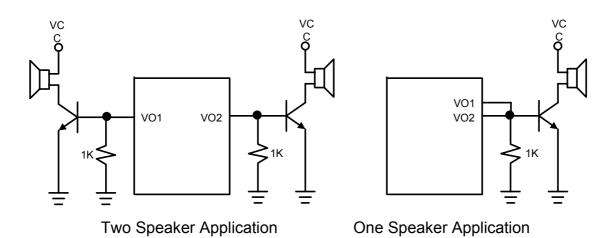
P33 can be modulated with 42KHz square wave before sent out to P33 pin. The IR signal can be achieved by this modulated signal.



5.9. 2 8-bit DAC

Two 8-bit current type digital-to-analog converters are built-in SN66012B. The relationship between input digital data and output analog current signal is listed in the following table. Also, the recommended application circuit is illustrated as follows.

Input data	Typical value of output current (mA)
0	0
1	3/255
N	n*(3/255)
255	3





6 ABSOLUTE MAXIMUM RATING

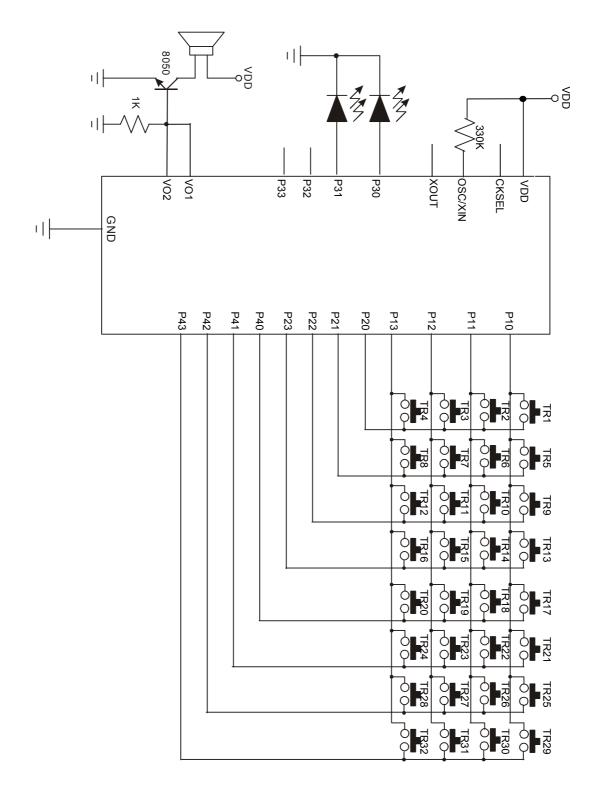
Items	Symbol	Min	Max	Unit.
Supply Voltage	V _{DD} -V	-0.3	6.0	V
Input Voltage	V _{IN}	V _{SS} -0.3	V _{DD} +0.3	V
Operating Temperature	T _{OP}	0	55.0	°C
Storage Temperature	T _{STG}	-55.0	125.0	°C

7 ELECTRICAL CHARACTERISTICS

Item	Sym.	Min.	Тур.	Max.	Unit	Condition
Operating Voltage	V_{DD}	2.4	3.0	5.1	V	
Standby Current	I _{SBY}	-	2	3	иA	V _{DD} =3V
		-	5	7		V _{DD} =5V
Operating Current	I _{OPR}	-	350	400	иA	V_{DD} =3V, no load
		-	1.3	2	mA	V _{DD} =5V, no load
Input Current of P1	I _{IH}	-	3	10	uА	V _{DD} =3V, V _{IN} =3V
		-	10	30		V _{DD} =5V, V _{IN} =5V
Drive Current of P2, P3, P4	I _{OD}	1.5	2	-	mА	V _{DD} =3V, V _O =2.6V
		3	5	-		V _{DD} =5V, V _O =4.2V
Sink Current of P2, P3, P4	l _{os}	2	3	-	mА	V _{DD} =3V, V _O =0.4V
		6	8	-		V _{DD} =5V, V _O =0.8V
VO1/VO2 Output Current	I _{VO}	2	3	4	mА	V _{DD} =3V, V _O =0.7V
		2	3	4		V _{DD} =5V, V _O =0.7V
Oscillation Freq.	Fosc	-	2	-	MHz	V _{DD} =3V,
						ROSC=330K
IR Carrier Frequency	Fir	-	41.7	-	KHz	Fosc=2MHz

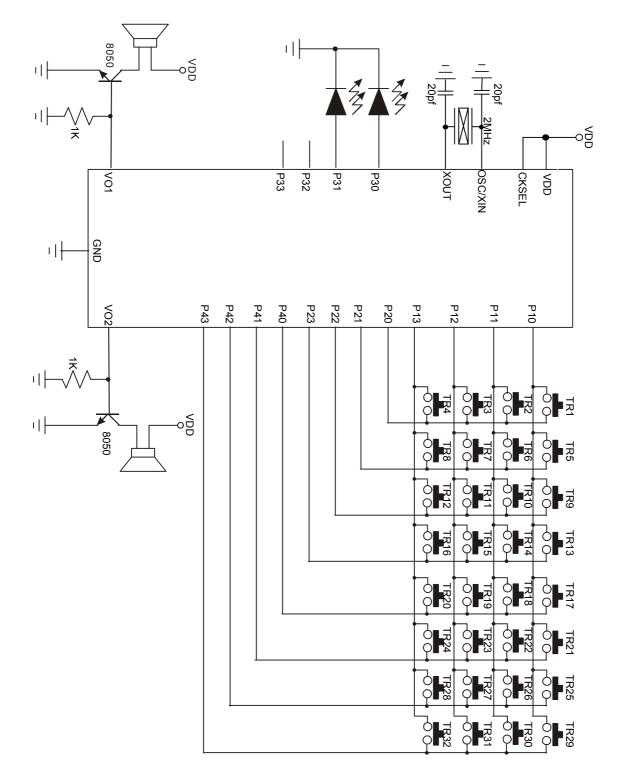


8 APPLICATION CIRCUIT



Crystal Oscillator One Speaker Output 32 Scan Keys

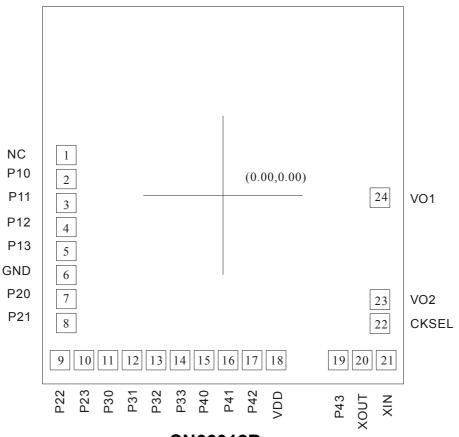




Crystal Oscillator Two Speaker Output 32 Scan Keys



9 BONDING PAD



SN66012B

Note: The substrate MUST be connected to GND in PCB layout.



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